

RoHS

COMPLIANT

**Vishay Siliconix** 

## **Buffered H-Bridge Driver with Integrate MOSFET**

#### DESCRIPTION

The Si9986 is an integrated, buffered H-bridge with TTL compatible inputs and the capability of delivering a continuous 1 A at  $V_{DD}$  = 12 V (room temperature) at switching rates up to 200 kHz. Internal logic prevents the upper and lower outputs of either half-bridge from being turned on simultaneously. Unique input codes allow both outputs to be forced low (for braking) or forced to a high impedance level.

The Si9986 is available in both standard and lead (Pb)-free, 8-pin SOIC packages, specified to operate over a voltage range of 3.8 V to 13.2 V, and the commercial temperature range of 0 °C to 70 °C (C suffix) and the industrial temperature range of - 40 °C to 85 °C (D suffix).

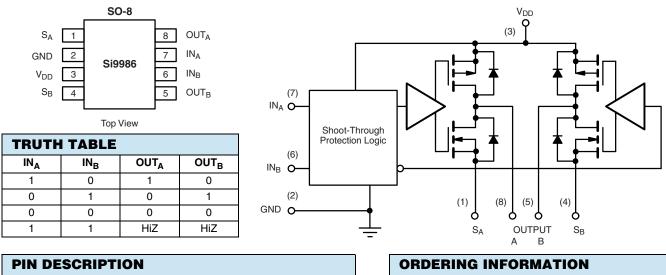
#### **FEATURES**

- 1 A H-bridge
- 200 kHz switching rate
- Shoot-through limited
- TTL compatible inputs
- 3.8 V to 13.2 V operating range
- Surface mount packaging

#### APPLICATIONS

- VCM driver
- Brushed motor driver
- Stepper motor driver
- Power converter
- Optical disk drives
- Power supplies
- High performance servo

#### FUNCTIONAL BLOCK DIAGRAM, PIN CONFIGURATION AND TRUTH TABLE



PIN DESCRIPTION					
Pin Number	Name	Function			
1	S <sub>A</sub>	Source of the low-side MOSFET on bridge arm A			
2	GND	Ground			
3	V <sub>DD</sub>	IC power supply			
4	SB	Source of the low-side MOSFET on bridge arm B			
5	OUT <sub>B</sub>	Center tap of bridge arm B. Connects to one end of the load			
6	IN <sub>B</sub>	Input signal to control bridge arm B			
7	IN <sub>A</sub>	Input signal to control bridge arm A			
8	OUT <sub>A</sub>	Center tap of bridge arm A. Connects to the other end of the load			

\* Pb containing terminations are not RoHS compliant, exemptions may apply.

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Temperature Part Number Package Range Si9986CY-T1 0 °C to 70 °C Tape and reel - 40 °C to 85 °C Si9986DY-T1 Si9986CY-T1-E3 0 °C to 70 °C Lead (Pb)-free - 40 °C to 85 °C Tape and reel Si9986DY-T1-E3 Si9986CY 0 °C to 70 °C Bulk (tubes) Si9986DY - 40 °C to 85 °C

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ABSOLUTE MAXIMUM RATINGS <sup>a</sup>					
Parameter		Limit	Unit		
Voltage on any Pin with Respect to Ground		- 0.3 to V <sub>DD</sub> + 0.3			
Voltage on Pins 5, 8 with Respect to Ground		- 1 to V <sub>DD</sub> + 1	V		
Voltage on Pins 1, 4		- 0.3 to GND + 1			
Peak Output Current		1.5	А		
Storage Temperature		- 65 to 150			
Maximum Junction Temperature (T <sub>J</sub> )		150			
Maximum V <sub>DD</sub>		15	V		
Power Dissipation <sup>b</sup>	1	W			
$\Theta_{JA}$		100	°C/W		
Operating Temperature Range	Si9986CY	0 to 70	°C		
Operating temperature hange	Si9986DY	- 45 to 85	C		

Notes:

a. Device mounted with all leads soldered or welded to PC board. b. Derate 10 mW/°C above 25 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE					
Parameter	Limit	Unit			
V <sub>DD</sub>	3.8 to 13.2	V			
Maximum Junction Temperature (T <sub>J</sub> )	125	°C			

		Test Conditions Unless Otherwise Specified $V_{DD} = 3.8$ to 13.2 V S <sub>A</sub> at GND, S <sub>B</sub> at GND		Limits C Suffix, 0 °C to 70 °C D Suffix, - 40 °C to 85 °C				
Parameter	Symbol			Min <sup>a</sup>	Тур <sup>ь</sup>	Max <sup>a</sup>	Unit	
Input				•				
Input Voltage High	V <sub>INH</sub>			2			v	
Input Voltage Low	V <sub>INL</sub>					1	v	
Input Current with Input Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 2 V				1	μA	
Input Current with Input Voltage Low	I <sub>INL</sub>	$V_{IN} = 0 V$		- 1			μА	
Output								
Output Voltage High		l <sub>OUT</sub> = - 500 mA	V <sub>DD</sub> = 10.8 V	10.5	10.7		-	
	V <sub>OUTH</sub>		V <sub>DD</sub> = 4.5 V	4.1	4.3			
		I <sub>OUT</sub> = - 300 mA, V <sub>DD</sub> = 3.8 V		3.4	3.7		v	
Output Voltage Low	V <sub>OUTL</sub>	I <sub>OUT</sub> = 500 mA	V <sub>DD</sub> = 10.8 V		0.2	0.3		
			V <sub>DD</sub> = 4.5 V		0.2	0.4		
		I <sub>OUT</sub> = 300 mA, V <sub>DD</sub> = 3.8 V			0.1	0.4	1	
Output Leakage Current High	I <sub>OLH</sub>	$IN_{A} = IN_{B} \ge 2 V, V_{OUT} = V_{DD} = 13.2 V$		- 10	0			
Output Leakage Current Low	I <sub>OLL</sub>	$V_{OUT} = 0, V_{DD} = 13.2 V$			0	10	μA	
Output V Clamp High	V <sub>CLH</sub>	$IN_A = IN_B \ge 2 V$	I <sub>OUT</sub> = 100 mA		V <sub>DD</sub> + 0.7		v	
Output V Clamp Low	V <sub>CLL</sub>	$IIN_A = IIN_B \ge 2$ V	I <sub>OUT</sub> = - 100 mA		- 0.7		v	
Supply			•	•				
V Supply Current		IN = 100 kHz, V <sub>DD</sub> = 5 V			2		mA	
V <sub>DD</sub> Supply Current	I <sub>DD</sub>	$IN_A = IN_B = 4.5 V, V_{DD} = 5.5 V$				300	μΑ	
Dynamic				•	•			
Propagation Dolov Time	T <sub>PLH</sub>	V <sub>DD</sub> = 5 V			300		nS	
Propogation Delay Time	T <sub>PHL</sub>				100			

Notes:

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

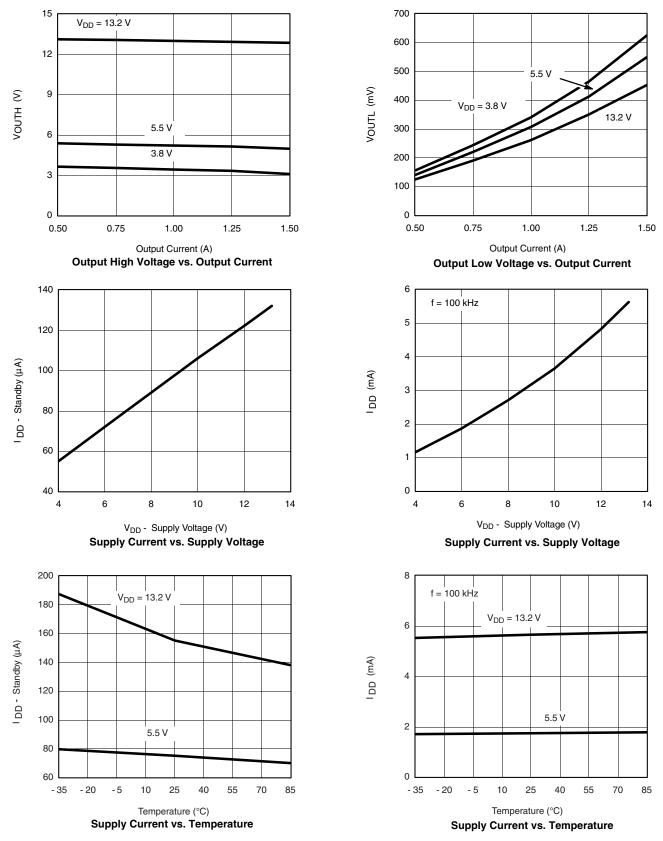
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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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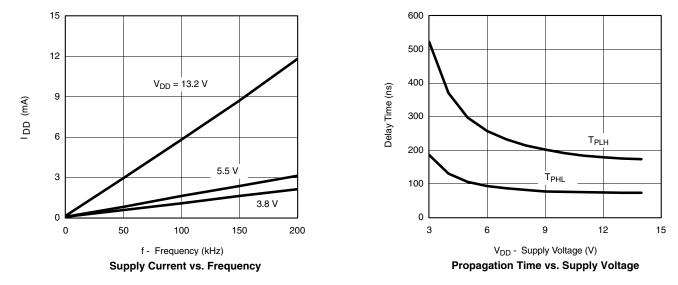
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#### Si9986

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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?70007">www.vishay.com/ppg?70007</a>.

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## Package Information

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## SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES		
DIM	Min	Мах	Min	Max	
A	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					



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